CMOS Digital Integrated Circuits Silicon Monolithic

# 74VHC164FT

#### 1. Functional Description

• 8-Bit Shift Register (S-IN, P-OUT)

#### 2. General

The 74VHC164FT is an advanced high speed CMOS 8-BIT SERIAL-IN PARALLEL-OUT SHIFT REGISTER fabricated with silicon gate C<sup>2</sup>MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

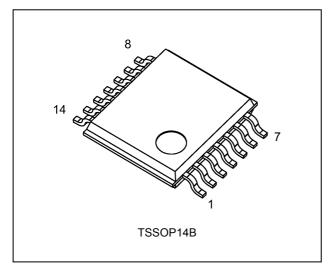
It consists of serial-in, parallel-out 8-bit shift register with a CLOCK input and an overriding  $\overline{\text{CLEAR}}$  input. Two serial data inputs (A, B) are provided so that one may be used as a data enable.

An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

#### 3. Features

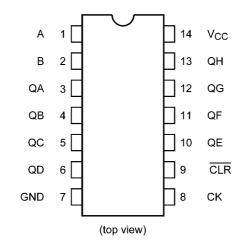
- (1) AEC-Q100 (Rev. H) (Note 1)
- (2) Wide operating temperature range:  $T_{opr} = -40$  to 125 °C
- (3) High speed:  $f_{MAX} = 175$  MHz (typ.) at  $V_{CC} = 5$  V
- (4) Low power dissipation:  $I_{CC} = 4.0 \ \mu A \ (max) \ at \ T_a = 25 \ ^{\circ}C$
- (5) High noise immunity:  $V_{\text{NIH}} = V_{\text{NIL}} = 28 \% V_{\text{CC}}$  (min)
- (6) Power-down protection is provided on all inputs.
- (7) Balanced propagation delays:  $t_{PLH} \approx t_{PHL}$
- (8) Wide operating voltage range:  $V_{CC(opr)} = 2.0 \text{ V to } 5.5 \text{ V}$
- (9) Low noise:  $V_{OLP} = 0.8 V (max)$
- (10) Pin and function compatible with the 74 series (AC/HC/AHC etc.) 164 type.
- Note 1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales representative.

#### 4. Packaging

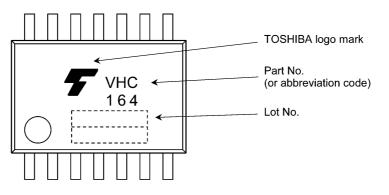


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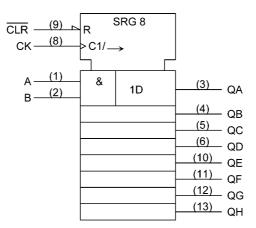
### **TOSHIBA** 5. Pin Assignment



#### 6. Marking



7. IEC Logic Symbol



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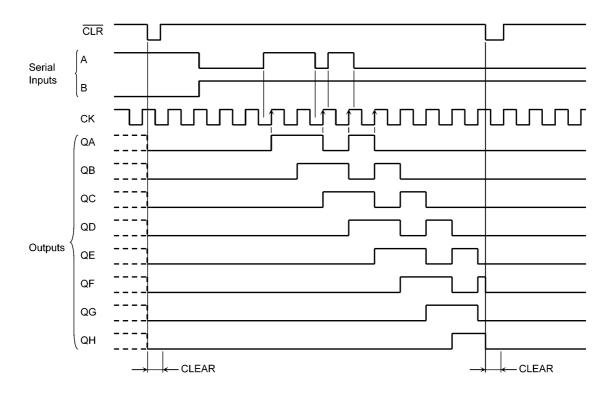
#### 8. Truth Table

|   | Inputs |       |           |           | Outputs |  |     |  |  |
|---|--------|-------|-----------|-----------|---------|--|-----|--|--|
|   | СК     | Seria | Serial IN |           | QA QB   |  | QH  |  |  |
|   | OK     | А     | В         | QA        |         |  | QII |  |  |
| L | Х      | Х     | Х         | L         | L       |  | L   |  |  |
| н |        | Х     | Х         | No Change |         |  |     |  |  |
| н |        | L     | х         | L         | QAn     |  | QGn |  |  |
| н |        | Х     | L         | L         | QAn     |  | QGn |  |  |
| н |        | н     | н         | н         | QAn     |  | QGn |  |  |

#### X: Don't care

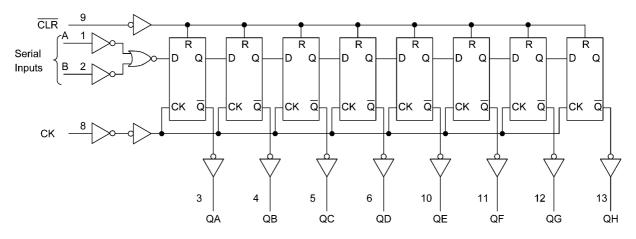
 $QA_n$  to  $QG_n$ : The level of QA to QG, respectively, before the most recent positive edge of the CK.

#### 9. Timing Diagrams



## TOSHIBA

#### 10. System Diagram



#### 11. Absolute Maximum Ratings (Note)

| Characteristics                 | Symbol           | Note     | Rating                        | Unit |
|---------------------------------|------------------|----------|-------------------------------|------|
| Supply voltage                  | V <sub>CC</sub>  |          | -0.5 to 7.0                   | V    |
| Input voltage                   | V <sub>IN</sub>  |          | -0.5 to 7.0                   | V    |
| Output voltage                  | V <sub>OUT</sub> |          | -0.5 to V <sub>CC</sub> + 0.5 | V    |
| Input diode current             | I <sub>IK</sub>  |          | -20                           | mA   |
| Output diode current            | I <sub>OK</sub>  |          | ±20                           | mA   |
| Output current                  | I <sub>OUT</sub> |          | ±25                           | mA   |
| V <sub>CC</sub> /ground current | I <sub>CC</sub>  |          | ±75                           | mA   |
| Power dissipation               | PD               | (Note 1) | 180                           | mW   |
| Storage temperature             | T <sub>stg</sub> |          | -65 to 150                    | C°   |

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: 180 mW in the range of T<sub>a</sub> = -40 to 85 °C. From T<sub>a</sub> = 85 to 125 °C a derating factor of -3.25 mW/°C shall be applied until 50 mW.

#### 12. Operating Ranges (Note)

| Characteristics           | Symbol           | Test Condition         | Rating               | Unit |
|---------------------------|------------------|------------------------|----------------------|------|
| Supply voltage            | V <sub>CC</sub>  |                        | 2.0 to 5.5           | V    |
| Input voltage             | V <sub>IN</sub>  |                        | 0 to 5.5             | V    |
| Output voltage            | V <sub>OUT</sub> |                        | 0 to V <sub>CC</sub> | V    |
| Operating temperature     | T <sub>opr</sub> |                        | -40 to 125           | °C   |
| Input rise and fall times | dt/dv            | $V_{CC}$ = 3.3 ± 0.3 V | 0 to 100             | ns/V |
|                           |                  | $V_{CC}$ = 5 ± 0.5 V   | 0 to 20              |      |

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either  $V_{CC}$  or GND.

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#### **13. Electrical Characteristics**

#### 13.1. DC Characteristics (Unless otherwise specified, $T_a = 25$ °C)

| Characteristics           | Symbol          | Test Condition                                       | I                        | V <sub>CC</sub> (V) | Min                 | Тур. | Max                 | Unit |
|---------------------------|-----------------|--|--------------------------|---------------------|---------------------|------|---------------------|------|
| High-level input voltage  | VIH             | —  |                          | 2.0                 | 1.50                | _    | —                   | V    |
|                           |                 |  |                          | 3.0 to 5.5          | $V_{CC} \times 0.7$ | _    | _                   |      |
| Low-level input voltage   | VIL             | —  |                          | 2.0                 | —                   | _    | 0.50                | V    |
|                           |                 |  |                          | 3.0 to 5.5          | —                   | _    | $V_{CC} \times 0.3$ |      |
| High-level output voltage | V <sub>OH</sub> | V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> | I <sub>OH</sub> = -50 μA | 2.0                 | 1.9                 | 2.0  | —                   | V    |
|                           |                 |  |                          | 3.0                 | 2.9                 | 3.0  | —                   |      |
|                           |                 |  |                          | 4.5                 | 4.4                 | 4.5  | —                   |      |
|                           |                 |  | I <sub>OH</sub> = -4 mA  | 3.0                 | 2.58                | _    | —                   |      |
|                           |                 |  | I <sub>OH</sub> = -8 mA  | 4.5                 | 3.94                | _    | —                   |      |
| Low-level output voltage  | V <sub>OL</sub> | $V_{IN} = V_{IH} \text{ or } V_{IL}$                 | I <sub>OL</sub> = 50 μA  | 2.0                 | —                   | 0.0  | 0.1                 | V    |
|                           |                 |  |                          | 3.0                 | —                   | 0.0  | 0.1                 |      |
|                           |                 |  |                          | 4.5                 | —                   | 0.0  | 0.1                 |      |
|                           |                 |  | I <sub>OL</sub> = 4 mA   | 3.0                 | —                   | _    | 0.36                |      |
|                           |                 |  | I <sub>OL</sub> = 8 mA   | 4.5                 | _                   | _    | 0.36                |      |
| Input leakage current     | I <sub>IN</sub> | V <sub>IN</sub> = 5.5 V or GND                       |                          | 0 to 5.5            |                     |      | ±0.1                | μA   |
| Quiescent supply current  | I <sub>CC</sub> | V <sub>IN</sub> = V <sub>CC</sub> or GND             |                          | 5.5                 |                     | _    | 4.0                 | μA   |

#### 13.2. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C)

| Characteristics           | Symbol          | Test Con   | dition                   | V <sub>CC</sub> (V) | Min                 | Max                 | Unit |
|---------------------------|-----------------|--|--------------------------|---------------------|---------------------|---------------------|------|
| High-level input voltage  | V <sub>IH</sub> | —  |                          | 2.0                 | 1.50                | —                   | V    |
|                           |                 |  |                          | 3.0 to 5.5          | $V_{CC} \times 0.7$ | _                   |      |
| Low-level input voltage   | VIL             | _  |                          | 2.0                 | _                   | 0.50                | V    |
|                           |                 |  |                          | 3.0 to 5.5          | _                   | $V_{CC} \times 0.3$ |      |
| High-level output voltage | V <sub>OH</sub> | $V_{IN} = V_{IH}$ or $V_{IL}$                        | I <sub>OH</sub> = -50 μA | 2.0                 | 1.9                 | —                   | V    |
|                           |                 |  |                          | 3.0                 | 2.9                 | —                   |      |
|                           |                 |  |                          | 4.5                 | 4.4                 | _                   |      |
|                           |                 |  | I <sub>OH</sub> = -4 mA  | 3.0                 | 2.48                | —                   |      |
|                           |                 |  | I <sub>OH</sub> = -8 mA  | 4.5                 | 3.80                | —                   |      |
| Low-level output voltage  | V <sub>OL</sub> | V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> | I <sub>OL</sub> = 50 μA  | 2.0                 | _                   | 0.1                 | V    |
|                           |                 |  |                          | 3.0                 | —                   | 0.1                 |      |
|                           |                 |  |                          | 4.5                 | _                   | 0.1                 |      |
|                           |                 |  | I <sub>OL</sub> = 4 mA   | 3.0                 | _                   | 0.44                |      |
|                           |                 |  | I <sub>OL</sub> = 8 mA   | 4.5                 | _                   | 0.44                |      |
| Input leakage current     | I <sub>IN</sub> | V <sub>IN</sub> = 5.5 V or GND                       |                          | 0 to 5.5            |                     | ±1.0                | μA   |
| Quiescent supply current  | I <sub>CC</sub> | V <sub>IN</sub> = V <sub>CC</sub> or GND             |                          | 5.5                 |                     | 40.0                | μA   |

#### 13.3. DC Characteristics (Unless otherwise specified, Ta = -40 to 125 °C)

| Characteristics           | Symbol          | Test Cond   | dition                  | V <sub>CC</sub> (V) | Min                 | Max                 | Unit |
|---------------------------|-----------------|---|-------------------------|---------------------|---------------------|---------------------|------|
| High-level input voltage  | VIH             | —   |                         | 2.0                 | 1.50                | —                   | V    |
|                           |                 |   |                         | 3.0 to 5.5          | $V_{CC} \times 0.7$ | —                   |      |
| Low-level input voltage   | VIL             | _   |                         | 2.0                 | _                   | 0.50                | V    |
|                           |                 |   |                         | 3.0 to 5.5          | _                   | $V_{CC} \times 0.3$ |      |
| High-level output voltage | V <sub>OH</sub> | $V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -50 \ \mu\text{A}$ |                         | 2.0                 | 1.9                 | _                   | V    |
|                           |                 |   |                         | 3.0                 | 2.9                 |                     |      |
|                           |                 |   |                         | 4.5                 | 4.4                 | _                   |      |
|                           |                 |   | I <sub>OH</sub> = -4 mA | 3.0                 | 2.40                | —                   |      |
|                           |                 |   | I <sub>OH</sub> = -8 mA | 4.5                 | 3.70                | —                   |      |
| Low-level output voltage  | V <sub>OL</sub> | $V_{IN} = V_{IH} \text{ or } V_{IL}$                              | I <sub>OL</sub> = 50 μA | 2.0                 | _                   | 0.1                 | V    |
|                           |                 |   |                         | 3.0                 | _                   | 0.1                 |      |
|                           |                 |   |                         | 4.5                 | _                   | 0.1                 |      |
|                           |                 |   | I <sub>OL</sub> = 4 mA  | 3.0                 | _                   | 0.55                |      |
|                           |                 |   | I <sub>OL</sub> = 8 mA  | 4.5                 | _                   | 0.55                |      |
| Input leakage current     | I <sub>IN</sub> | V <sub>IN</sub> = 5.5 V or GND                                    |                         | 0 to 5.5            |                     | ±2.0                | μA   |
| Quiescent supply current  | I <sub>CC</sub> | V <sub>IN</sub> = V <sub>CC</sub> or GND                          |                         | 5.5                 | _                   | 80.0                | μA   |

#### 13.4. Timing Requirements (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

| Characteristics            | Symbol               | Test Condition | V <sub>CC</sub> (V)           | Limit | Unit |
|----------------------------|----------------------|----------------|-------------------------------|-------|------|
| Minimum pulse width (CK)   | $t_{w(L)}, t_{w(H)}$ | —              | $\textbf{3.3}\pm\textbf{0.3}$ | 5.0   | ns   |
|                            |                      |                | $5.0 \pm 0.5$                 | 5.0   |      |
| Minimum pulse width (CLR)  | t <sub>w(L)</sub>    | _              | $\textbf{3.3}\pm\textbf{0.3}$ | 5.0   | ns   |
|                            |                      |                | $5.0\pm0.5$                   | 5.0   |      |
| Minimum setup time         | t <sub>S</sub>       | _              | $\textbf{3.3}\pm\textbf{0.3}$ | 5.0   | ns   |
|                            |                      |                | $5.0\pm0.5$                   | 4.5   |      |
| Minimum hold time          | t <sub>h</sub>       | _              | $\textbf{3.3}\pm\textbf{0.3}$ | 0.0   | ns   |
|                            |                      |                | $5.0\pm0.5$                   | 1.0   |      |
| Minimum removal time (CLR) | t <sub>rem</sub>     | _              | $\textbf{3.3}\pm\textbf{0.3}$ | 2.5   | ns   |
|                            |                      |                | $5.0\pm0.5$                   | 2.5   |      |

# 13.5. Timing Requirements (Unless otherwise specified, $T_a$ = -40 to 85 °C, Input: $t_r$ = $t_f$ = 3 ns)

| Characteristics                          | Symbol                               | Test Condition | V <sub>CC</sub> (V)           | Limit | Unit |
|--|--------------------------------------|----------------|-------------------------------|-------|------|
| Minimum pulse width (CK)                 | t <sub>w(L)</sub> ,t <sub>w(H)</sub> | —              | $\textbf{3.3}\pm\textbf{0.3}$ | 5.0   | ns   |
|  |                                      |                | $5.0 \pm 0.5$                 | 5.0   |      |
| Minimum pulse width ( $\overline{CLR}$ ) | t <sub>w(L)</sub>                    | —              | $\textbf{3.3}\pm\textbf{0.3}$ | 5.0   | ns   |
|  |                                      |                | $5.0\pm0.5$                   | 5.0   |      |
| Minimum setup time                       | ts                                   | _              | $\textbf{3.3}\pm\textbf{0.3}$ | 6.0   | ns   |
|  |                                      |                | $5.0\pm0.5$                   | 4.5   |      |
| Minimum hold time                        | t <sub>h</sub>                       |                | $\textbf{3.3}\pm\textbf{0.3}$ | 0.0   | ns   |
|  |                                      |                | $5.0\pm0.5$                   | 1.0   |      |
| Minimum removal time (CLR)               | t <sub>rem</sub>                     |                | $\textbf{3.3}\pm\textbf{0.3}$ | 2.5   | ns   |
|  |                                      |                | $5.0\pm0.5$                   | 2.5   |      |

#### 13.6. Timing Requirements (Unless otherwise specified, T<sub>a</sub> = -40 to 125 °C, Input: t<sub>r</sub> = t<sub>f</sub> = 3 ns)

| Characteristics            | Symbol               | Test Condition | V <sub>CC</sub> (V) | Limit | Unit |
|----------------------------|----------------------|----------------|---------------------|-------|------|
| Minimum pulse width (CK)   | $t_{w(L)}, t_{w(H)}$ | _              | $3.3\pm0.3$         | 5.0   | ns   |
|                            |                      |                | $5.0\pm0.5$         | 5.0   |      |
| Minimum pulse width (CLR)  | t <sub>w(L)</sub>    | _              | $3.3\pm0.3$         | 5.0   | ns   |
|                            |                      |                | $5.0\pm0.5$         | 5.0   |      |
| Minimum setup time         | ts                   | _              | $3.3\pm0.3$         | 6.0   | ns   |
|                            |                      |                | $5.0\pm0.5$         | 4.5   | ]    |
| Minimum hold time          | t <sub>h</sub>       | _              | $3.3\pm0.3$         | 0.0   | ns   |
|                            |                      |                | $5.0\pm0.5$         | 1.0   |      |
| Minimum removal time (CLR) | t <sub>rem</sub>     | _              | $3.3\pm0.3$         | 3.5   | ns   |
|                            |                      |                | $5.0\pm0.5$         | 3.0   |      |

### 13.7. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

| Characteristics                                      | Symbol                             | Note     | Test Condition | V <sub>CC</sub> (V)           | C <sub>L</sub> (pF) | Min | Тур. | Max  | Unit |
|--|------------------------------------|----------|----------------|-------------------------------|---------------------|-----|------|------|------|
| Propagation delay time (CK-Q)                        | t <sub>PLH</sub> ,t <sub>PHL</sub> |          | —              | $\textbf{3.3}\pm\textbf{0.3}$ | 15                  | —   | 8.4  | 12.8 | ns   |
|  |                                    |          |                |                               | 50                  | _   | 10.9 | 16.3 |      |
|  |                                    |          |                | $5.0\pm0.5$                   | 15                  | _   | 5.8  | 9.0  |      |
|  |                                    |          |                |                               | 50                  |     | 7.3  | 11.0 |      |
| Propagation delay time ( $\overline{\text{CLR}}$ -Q) | t <sub>PHL</sub>                   |          | —              | $\textbf{3.3}\pm\textbf{0.3}$ | 15                  | _   | 8.3  | 12.8 | ns   |
|  |                                    |          |                |                               | 50                  | —   | 10.8 | 16.3 |      |
|  |                                    |          |                | $5.0\pm0.5$                   | 15                  | —   | 5.2  | 8.6  |      |
|  |                                    |          |                |                               | 50                  | —   | 6.7  | 10.6 |      |
| Maximum clock frequency                              | f <sub>MAX</sub>                   |          | —              | $\textbf{3.3}\pm\textbf{0.3}$ | 15                  | 80  | 125  | _    | MHz  |
|  |                                    |          |                |                               | 50                  | 50  | 75   | —    |      |
|  |                                    |          |                | $5.0\pm0.5$                   | 15                  | 125 | 175  | —    |      |
|  |                                    |          |                |                               | 50                  | 85  | 115  | —    |      |
| Input capacitance                                    | C <sub>IN</sub>                    |          |                |                               |                     |     | 4    | 10   | pF   |
| Power dissipation capacitance                        | C <sub>PD</sub>                    | (Note 1) |                |                               |                     |     | 76   | _    | pF   |

Note 1:  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.  $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}$ 

#### 13.8. AC Characteristics

#### (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

| Characteristics                | Symbol                             | Test Condition | $V_{CC}(V)$                   | $C_L (pF)$ | Min | Max  | Unit  |
|--------------------------------|------------------------------------|----------------|-------------------------------|------------|-----|------|-------|
| Propagation delay time (CK-Q)  | t <sub>PLH</sub> ,t <sub>PHL</sub> | —              | $\textbf{3.3}\pm\textbf{0.3}$ | 15         | 1.0 | 15.0 | ns    |
|                                |                                    |                |                               | 50         | 1.0 | 18.5 |       |
|                                |                                    |                | $5.0\pm0.5$                   | 15         | 1.0 | 10.5 |       |
|                                |                                    |                |                               | 50         | 1.0 | 12.5 |       |
| Propagation delay time (CLR-Q) | t <sub>PHL</sub>                   | —              | $\textbf{3.3}\pm\textbf{0.3}$ | 15         | 1.0 | 15.0 | ns    |
|                                |                                    |                |                               | 50         | 1.0 | 18.5 |       |
|                                |                                    |                | $5.0\pm0.5$                   | 15         | 1.0 | 10.0 |       |
|                                |                                    |                |                               | 50         | 1.0 | 12.0 |       |
| Maximum clock frequency        | f <sub>MAX</sub>                   | —              | $\textbf{3.3}\pm\textbf{0.3}$ | 15         | 65  | _    | MHz   |
|                                |                                    |                |                               | 50         | 45  | —    |       |
|                                |                                    |                | $5.0\pm0.5$                   | 15         | 105 | —    |       |
|                                |                                    |                |                               | 50         | 75  | _    |       |
| Input capacitance              | C <sub>IN</sub>                    | _              |                               |            | _   | 10   | pF    |
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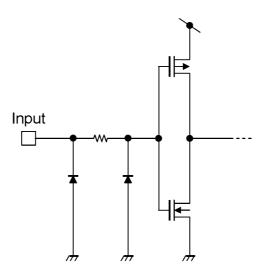
# 13.9. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 125 °C, Input: $t_r = t_f = 3$ ns)

| Characteristics                | Symbol                             | Test Condition | V <sub>CC</sub> (V)           | $C_L (pF)$ | Min | Max  | Unit |
|--------------------------------|------------------------------------|----------------|-------------------------------|------------|-----|------|------|
| Propagation delay time (CK-Q)  | t <sub>PLH</sub> ,t <sub>PHL</sub> | _              | $3.3\pm0.3$                   | 15         | 1.0 | 17.0 | ns   |
|                                |                                    |                |                               | 50         | 1.0 | 20.5 |      |
|                                |                                    |                | $5.0\pm0.5$                   | 15         | 1.0 | 12.0 |      |
|                                |                                    |                |                               | 50         | 1.0 | 14.0 |      |
| Propagation delay time (CLR-Q) | t <sub>PHL</sub>                   | —              | $\textbf{3.3}\pm\textbf{0.3}$ | 15         | 1.0 | 17.0 | ns   |
|                                |                                    |                |                               | 50         | 1.0 | 20.5 |      |
|                                |                                    |                | $5.0\pm0.5$                   | 15         | 1.0 | 11.5 |      |
|                                |                                    |                |                               | 50         | 1.0 | 13.5 |      |
| Maximum clock frequency        | f <sub>MAX</sub>                   | _              | $3.3\pm0.3$                   | 15         | 60  | _    | MHz  |
|                                |                                    |                |                               | 50         | 40  | _    | 1    |
|                                |                                    |                | $5.0\pm0.5$                   | 15         | 100 | _    |      |
|                                |                                    |                |                               | 50         | 65  | _    |      |
| Input capacitance              | C <sub>IN</sub>                    | _              |                               |            | _   | 10   | pF   |

#### 13.10. Noise Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

| Characteristics                              | Symbol           | Test Condition         | V <sub>CC</sub> (V) | Тур. | Limit | Unit |
|--|------------------|------------------------|---------------------|------|-------|------|
| Quiet output maximum dynamic V <sub>OL</sub> | V <sub>OLP</sub> | C <sub>L</sub> = 50 pF | 5.0                 | 0.5  | 0.8   | V    |
| Quiet output minimum dynamic V <sub>OL</sub> | V <sub>OLV</sub> | C <sub>L</sub> = 50 pF | 5.0                 | -0.5 | -0.8  | V    |
| Minimum high-level dynamic input voltage     | V <sub>IHD</sub> | C <sub>L</sub> = 50 pF | 5.0                 | _    | 3.5   | V    |
| Maximum low-level dynamic input voltage      | V <sub>ILD</sub> | C <sub>L</sub> = 50 pF | 5.0                 |      | 1.5   | V    |

#### 14. Internal Equivalent Circuit

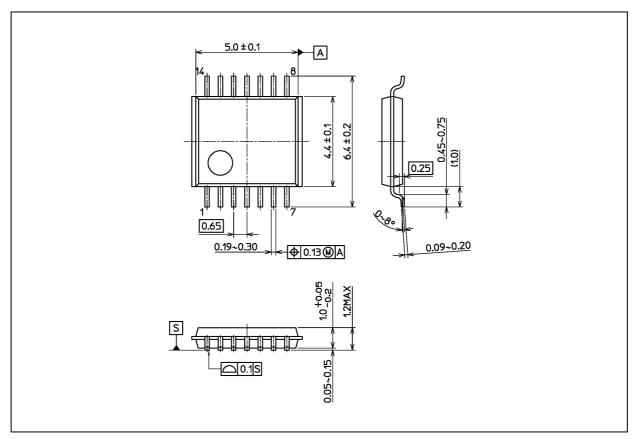




#### 74VHC164FT

#### **Package Dimensions**

Unit: mm



Weight: 0.054 g (typ.)

|                    | Package Name(s) |
|--------------------|-----------------|
| Nickname: TSSOP14B |                 |

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